

NPN HIGH POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/518

Devices

2N3771

2N3772

Qualified Level

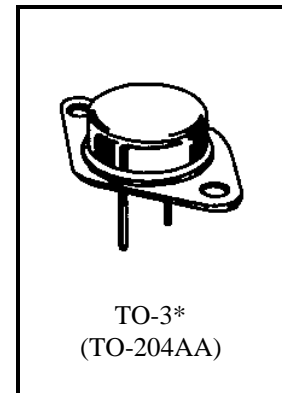
JANTX
JANTXV

MAXIMUM RATINGS

Ratings	Symbol	2N3771	2N3772	Unit
Collector-Emitter Voltage	V_{CEO}	40	60	Vdc
Collector-Base Voltage	V_{CBO}	50	100	Vdc
Emitter-Base Voltage	V_{EBO}	7.0	7.0	Vdc
Base Current	I_B	7.5	5.0	Adc
Collector Current	I_C	30	20	Adc
Total Power Dissipation	P_T	@ $T_A = +25^{\circ}C$ ⁽¹⁾	6.0	W
		@ $T_C = +25^{\circ}C$ ⁽²⁾	150	W
Operating & Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		$^{\circ}C$

1) Derate linearly 34.2 mW/ $^{\circ}C$ for $T_A > +25^{\circ}C$

2) Derate linearly 857 mW/ $^{\circ}C$ for $T_C > +25^{\circ}C$



*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristics	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Collector-Base Breakdown Voltage $I_C = 200$ mAdc	2N3771 2N3772	$V_{(BR)CEO}$	40 60	Vdc
Collector-Emitter Breakdown Voltage $I_C = 200$ mAdc, $R_{BE} = 100 \Omega$	2N3771 2N3772	$V_{(BR)CER}$	45 70	Vdc
Collector-Emitter Breakdown Voltage $I_C = 200$ mAdc, $V_{BE} = -1.5$ Vdc	2N3771 2N3772	$V_{(BR)CEX}$	50 90	Vdc
Collector-Emitter Cutoff Current $V_{CE} = 30$ Vdc $V_{CE} = 50$ Vdc	2N3771 2N3772	I_{CEO}	5.0 5.0	mAdc
Emitter-Base Cutoff Current $V_{BE} = 7.0$ Vdc	2N3771 2N3772	I_{EBO}	2.0	mAdc
Collector-Emitter Cutoff Current $V_{BE} = 1.5$ Vdc, $V_{CE} = 50$ Vdc $V_{BE} = 1.5$ Vdc, $V_{CE} = 100$ Vdc	2N3771 2N3772	I_{CEX}	500 500	μ Adc

2N3771, 2N3772 JAN SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics		Symbol	Min.	Max.	Unit
ON CHARACTERISTICS ⁽³⁾					
Forward-Current Transfer Ratio		h_{FE}			
$I_C = 15 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$	2N3771		15	60	
$I_C = 10 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$	2N3772		15	60	
$I_C = 1.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$	Both		40	-	
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$			
$I_C = 15 \text{ Adc}, I_B = 1.5 \text{ Adc}$	2N3771			1.5	Vdc
$I_C = 30 \text{ Adc}, I_B = 6.0 \text{ Adc}$	2N3771			4.0	
$I_C = 10 \text{ Adc}, I_B = 1.0 \text{ Adc}$	2N3772			1.2	
$I_C = 20 \text{ Adc}, I_B = 4.0 \text{ Adc}$	2N3772			4.0	
Base-Emitter Voltage (non-saturated)		V_{BE}			
$I_C = 15 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$	2N3771			2.3	Vdc
$I_C = 10 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$	2N3772			2.0	

DYNAMIC CHARACTERISTICS

Small-Signal Cutoff Frequency		h_{fe}	40		
$I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$					
Magnitude of Common Emitter Small-Signal Short-Circuit Forward-Current Transfer		$ h_{fe} $	6.0	30	
$I_C = 1.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}, f = 100 \text{ kHz}$					
Output Capacitance		C_{obo}		1200	p^f
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$					

SWITCHING CHARACTERISTICS

Turn-On Time		t_{on}			
$V_{CC} = 30 \text{ Vdc}; I_C = 15 \text{ Adc}; I_{B1} = 1.5 \text{ Adc}$	2N3771			10	μs
$V_{CC} = 30 \text{ Vdc}; I_C = 10 \text{ Adc}; I_{B1} = 1.0 \text{ Adc}$	2N3772			8.0	
Turn-Off Time		t_{off}			
$V_{CC} = 30 \text{ Vdc}; I_C = 15 \text{ Adc}; I_{B1} = 1.5 \text{ Adc}; I_{B2} = -1.5 \text{ Adc}$	2N3771			12	μs
$V_{CC} = 30 \text{ Vdc}; I_C = 10 \text{ Adc}; I_{B1} = 1.0 \text{ Adc}; I_{B2} = -1.0 \text{ Adc}$	2N3772			10	

SAFE OPERATING AREA

DC Tests	
$T_C = +25^\circ C, 1 \text{ Cycle}, t = 1.0 \text{ s}$	
Test 1 (2N3771 only)	
$V_{CE} = 5.0 \text{ Vdc}, I_C = 30 \text{ Adc}$	
Test 2 (2N3771 only)	
$V_{CE} = 40 \text{ Vdc}, I_C = 3.75 \text{ Adc}$	
Test 3 (2N3772 only)	
$V_{CE} = 7.5 \text{ Vdc}, I_C = 20 \text{ Adc}$	
Test 4 (2N3772 only)	
$V_{CE} = 60 \text{ Vdc}, I_C = 2.5 \text{ Adc}$	
Clamped Inductive	
$T_A = +25^\circ C; \text{duty cycle} \leq 10\%; R_S = 0.1 \Omega$	
Test 1 (2N3771 only)	
$R_{BB1} = 2.0 \Omega; V_{BB1} \leq 14 \text{ Vdc}; R_{BB2} = 100 \Omega; V_{CC} = 20 \pm 5.0 \text{ Vdc}; V_{BB2} = 1.5 \text{ Vdc}; I_C = 30 \text{ Adc}; R_L \leq 0.67 \Omega; L = 5.0 \text{ mH}$	
Test 2 (2N3772 only)	
$R_{BB1} = 2.0 \Omega; V_{BB1} \leq 10 \text{ Vdc}; R_{BB2} = 100 \Omega; V_{CC} = 40 \pm 5.0 \text{ Vdc}; V_{BB2} = 1.5 \text{ Vdc}; I_C = 20 \text{ Adc}; R_L \leq 2.0 \Omega; L = 5.0 \text{ mH}$	

(3) Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.